DESCRIPTION

The A3355 is an NPN silicon Epitaxial Transistor. It has High frequency.

The A3355 is available in SOT-23 and TO-92 packages

ORDERING INFORMATION

Package Type	Part Number			
00T 00	F2	A3355E3R		
SOT-23	E3	A3355E3VR		
TO-92	Z	A3355ZY		
		A3355ZVY		
	R: Tape & Reel			
Note	V: Halogen free Package			
Note	Y: A : Ammo Package			
	B : Bulk Package			
AiT provides all RoHS products				

Suffix "V" means Halogen free Package

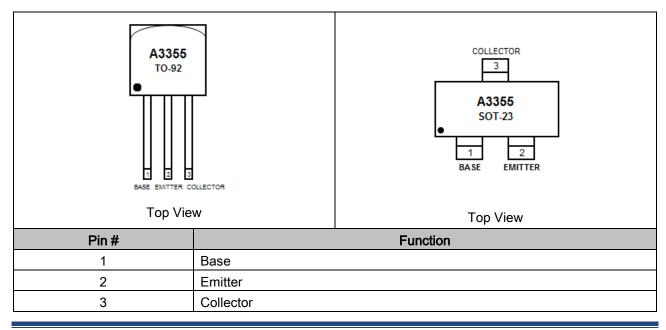
FEATURES

- Collector Current: 200mA (Max)
- High Frequency: 4.5GHz (Typ)
- Collector-Emitter Voltage: 12V
- Low noise and high gain bandwidth product
- High power gain
- Available in SOT-23 and TO-92 Packages

APPLICATION

- VHF
- UHF
- CATV

PIN DESCRIPTION



ABSOLUTE MAXIMUM RATING

T=25°C

1 20 0		
V _{CBO} , Collector-Base Voltage		20V
V _{CEO} , Collector-Emitter Voltage		12V
V _{EBO} , Emitter-Base Voltage		3V
Ic, Collector Current		200mA
Pc, Collector Power Dissipation	SOT-23	0.6W
	TO-92	0.2W
T _J , Junction Temperature		150℃
Tstg, Storage Temperature		-65°C~ +150°C

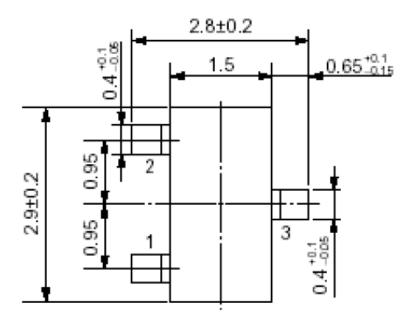
ELECTRICAL CHARACTERISTICS

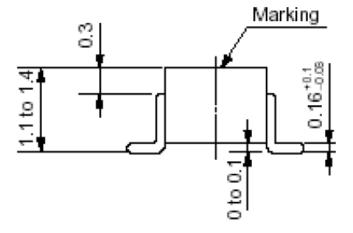
T=25°C

Parameter	Symbol	Condition	Min	Тур	Max	Unit		
Collector-Base Breakdown Voltage	ВУсво	I _C =10uA	20			V		
Collector-Emitter Breakdown Voltage	BV _{CEO}	I _C =1mA	12			V		
Emitter-Base Breakdown Voltage	BV_{EBO}	I _E =10uA	3			V		
Collector Cutoff Current	Ісво	V _{CB} =10V			1	uA		
Emitter Cutoff Current	I _{EBO}	V _{EB} =1V			1	uA		
DC Current Transfer Ratio	H_{FE}	V _{CE} =10V, I _C =20mA	90	150	220			
RF Characteristics								
Transition Frequency	F⊤	V _{CE} =10V, I _C =20mA		4.5		GHz		

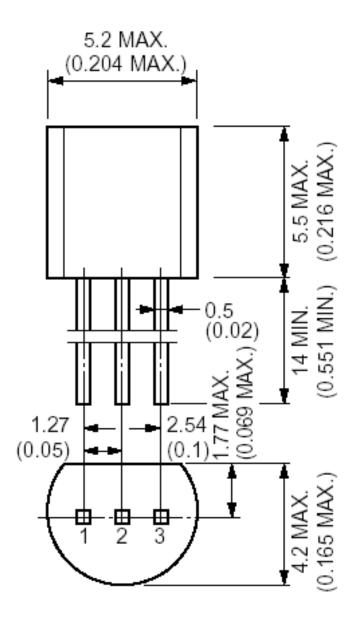
PACKAGE INFORMATION

Dimension in SOT-23 Package (Unit: mm)





Dimension in TO-92 (Unit: mm)



IMPORTANT NOTICE

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